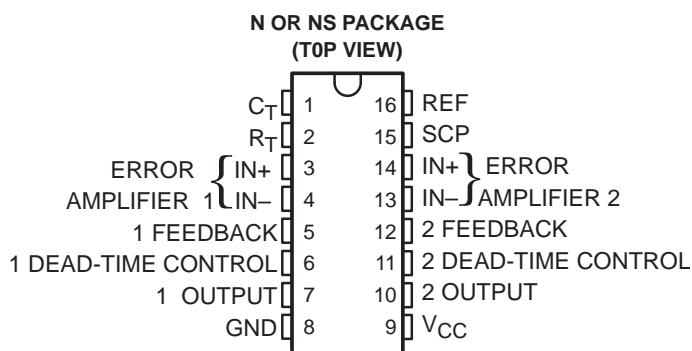


TL1453C DUAL PULSE-WIDTH-MODULATION CONTROL CIRCUIT

SLVS039A – FEBRUARY 1990 – REVISED DECEMBER 1990

- Complete PWM Power Control Circuitry
- Completely Synchronized Operation
- Internal Undervoltage Lockout Protection
- Wide Supply Voltage Range
- Oscillator Frequency . . . 500 kHz Max
- Variable Dead Time Provides Control Over Total Range
- Internal Regulator Provides a Stable 2.5-V Reference Supply



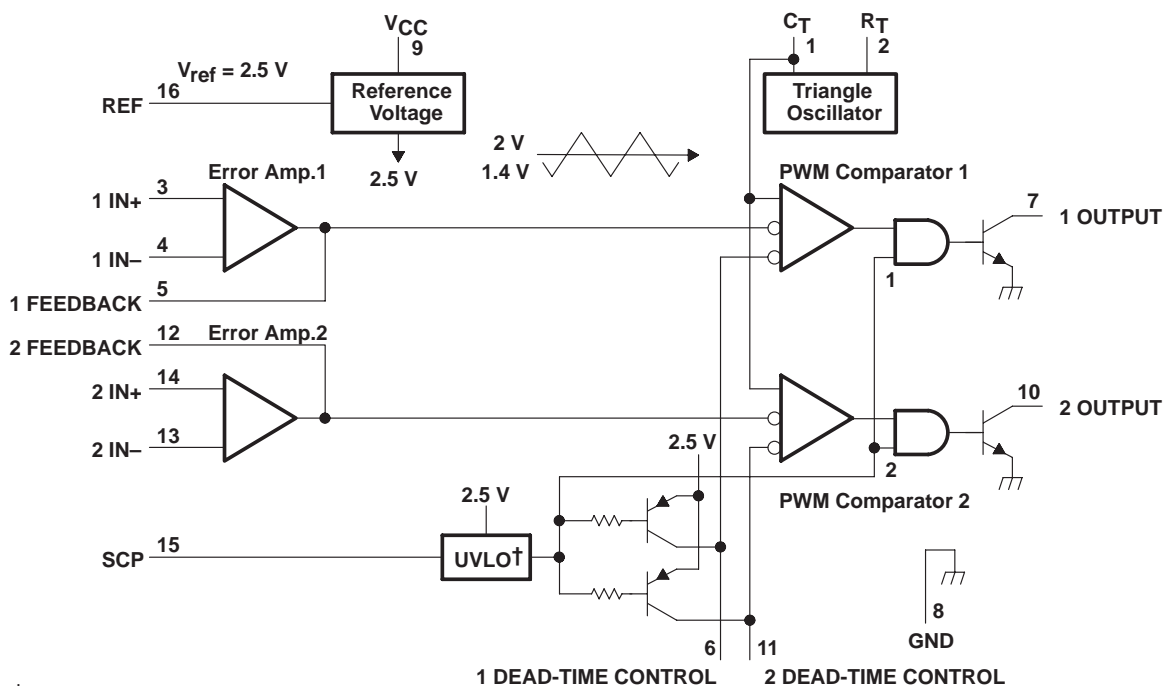
description

The TL1453C incorporates the functions required in the construction of two pulse-width-modulation control circuits on a single monolithic chip. Designed primarily for power supply control, the TL1453C contains an on-chip 2.5-V regulator, two error amplifiers, an adjustable oscillator, two dead-time comparators, undervoltage lockout circuitry, and dual common-emitter output transistor circuits.

The uncommitted output transistors provide common-emitter output capability for each controller. The internal amplifiers exhibit a common-mode voltage range from 1.05 V to 1.45 V. The dead-time control comparator has no offset unless externally altered and may be used to provide 0% to 100% dead time. The on-chip oscillator may be operated by terminating R_T (pin 2) and C_T (pin 1). During low- V_{CC} conditions, the undervoltage lockout control circuit feature inhibits the output until the internal circuitry is operational.

The TL1453C is characterized for operation from -20°C to 85°C .

functional block diagram



PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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TL1453C

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V_{CC} (see Note 1)	41 V
Amplifier input voltage	20 V
Collector output voltage	51 V
Collector output current	21 mA
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T_A	-20°C to 85°C
Storage temperature range	-65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

NOTE 1: All voltage values are with respect to network ground terminal.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 85^\circ\text{C}$ POWER RATING
N	1000 mW	8 mW/°C	520 mW
NS	725 mW	5.8 mW/°C	397 mW

recommended operating conditions

	MIN	MAX	UNIT
Supply voltage, V_{CC}	3.6	40	V
Amplifier input voltage, V_I	1.05	1.45	V
Collector output voltage, V_O		50	V
Collector output current		20	mA
Current into feedback terminal		45	μA
Feedback resistor, R_F	100		$\text{k}\Omega$
Timing capacitor, C_T	150	15000	pF
Timing resistor, R_T	5.1	100	$\text{k}\Omega$
Oscillator frequency	1	500	kHz
Operating free-air temperature, T_A	-20	85	°C

electrical characteristics over recommended operating free-air temperature range, $V_{CC} = 6\text{ V}$, $f = 200\text{ kHz}$ (unless otherwise noted)

reference section

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
Output voltage (pin 16)	$I_O = 1\text{ mA}$	2.4	2.5	2.6	V
Output voltage change with temperature	$T_A = -20^\circ\text{C}$ to 25°C		-0.1%	$\pm 1\%$	
	$T_A = 25^\circ\text{C}$ to 85°C		-0.2%	$\pm 1\%$	
Input regulation	$V_{CC} = 3.6\text{ V}$ to 40 V		2	12.5	mV
Output regulation	$I_O = 0.1\text{ mA}$ to 1 mA		1	7.5	mV
Short-circuit output current	$V_O = 0$	3	10	30	mA

† All typical values are at $T_A = 25^\circ\text{C}$.



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electrical characteristics over recommended operating free-air temperature range, $V_{CC} = 6\text{ V}$, $f = 200\text{ kHz}$ (unless otherwise noted) (continued)

undervoltage lockout section

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
Upper threshold voltage (pin 9)	$I_{Oref} = 0.1\text{ mA}$, $T_A = 25^\circ\text{C}$		2.72		V
Lower threshold voltage (pin 9)	$I_{Oref} = 0.1\text{ mA}$, $T_A = 25^\circ\text{C}$		2.6		V
Hysteresis (pin 9)	$I_{Oref} = 0.1\text{ mA}$, $T_A = 25^\circ\text{C}$	80	120		mV

oscillator section

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
Frequency	$C_T = 330\text{ pF}$, $R_T = 10\text{ k}\Omega$		200		kHz
Standard deviation of frequency	V_{CC} , T_A , R_T , C_T values are constant		10%		
Frequency change with voltage	$V_{CC} = 3.6\text{ V to }40\text{ V}$		1%		
Frequency change with temperature	$T_A = -20^\circ\text{C to }25^\circ\text{C}$		-0.4%	$\pm 2\%$	
	$T_A = 25^\circ\text{C to }85^\circ\text{C}$		-0.2%	$\pm 2\%$	

dead-time control section

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
Input bias current (pins 6 and 11)				1	μA
Input threshold voltage at $f = 10\text{ kHz}$ (pins 6 and 11)	Zero duty cycle		2.05	2.25	V
	Maximum duty cycle	1.2	1.45		

error-amplifier section

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
Input offset voltage	V_O (pins 5 and 12) = 1.25 V			± 6	mV
Input offset current	V_O (pins 5 and 12) = 1.25 V			± 100	nA
Input bias current	V_O (pins 5 and 12) = 1.25 V		160	500	nA
Common-mode input voltage range	$V_{CC} = 3.6\text{ V to }40\text{ V}$	1.05 to 1.45			V
Open-loop voltage amplification	$R_F = 200\text{ k}\Omega$	70	80		dB
Unity-gain bandwidth			1.5		MHz
Common-mode rejection ratio		60	80		dB
Positive output voltage swing		$V_{ref} - 0.1$			V
Negative output voltage swing				1	V
Output (sink) current (pins 5 and 12)	$V_{ID} = -0.1\text{ V}$, $V_O = 1.25\text{ V}$	0.5	1.6		mA
Output (source) current (pins 5 and 12)	$V_{ID} = 0.1\text{ V}$, $V_O = 1.25\text{ V}$	-45	-70		μA

output section

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
Collector off-state current	$V_{CC} = 0$, $V_O = 50\text{ V}$			10	μA
	$V_O = 50\text{ V}$			10	
Output saturation voltage	$I_O = 10\text{ mA}$		1.2	2	V
Short-circuit output current	$V_O = 6\text{ V}$		90		mA

† All typical values are at $T_A = 25^\circ\text{C}$.



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electrical characteristics over recommended operating free-air temperature range, $V_{CC} = 6\text{ V}$, $f = 200\text{ kHz}$ (unless otherwise noted) (continued)

pwm comparator section

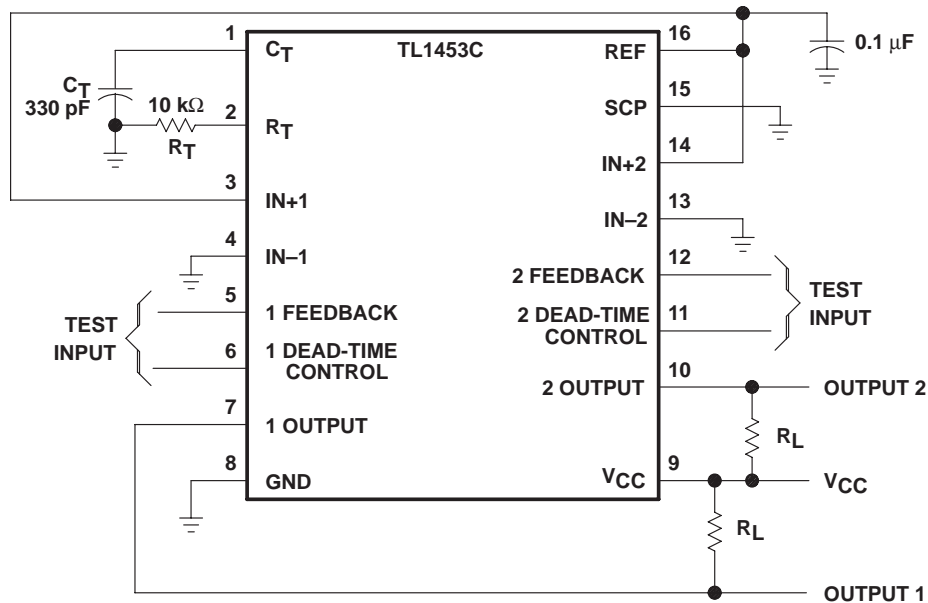
PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
Input threshold voltage at $f = 10\text{ kHz}$ (pins 5 and 12)	Zero duty cycle		2.05	2.25	V
	Maximum duty cycle	1.2	1.45		
Input (sink) current (pins 5 and 12)	$V_I = 1.25\text{ V}$	0.5	1.6		mA
Input (source) current (pins 5 and 12)	$V_I = 1.25\text{ V}$	-45	-70		μA

total device

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
Standby supply current	Off-state		1.3	1.8	mA
Average supply current	$R_T = 10\text{ k}\Omega$		1.7	2.4	mA

† All typical values are at $T_A = 25^\circ\text{C}$.

test circuit



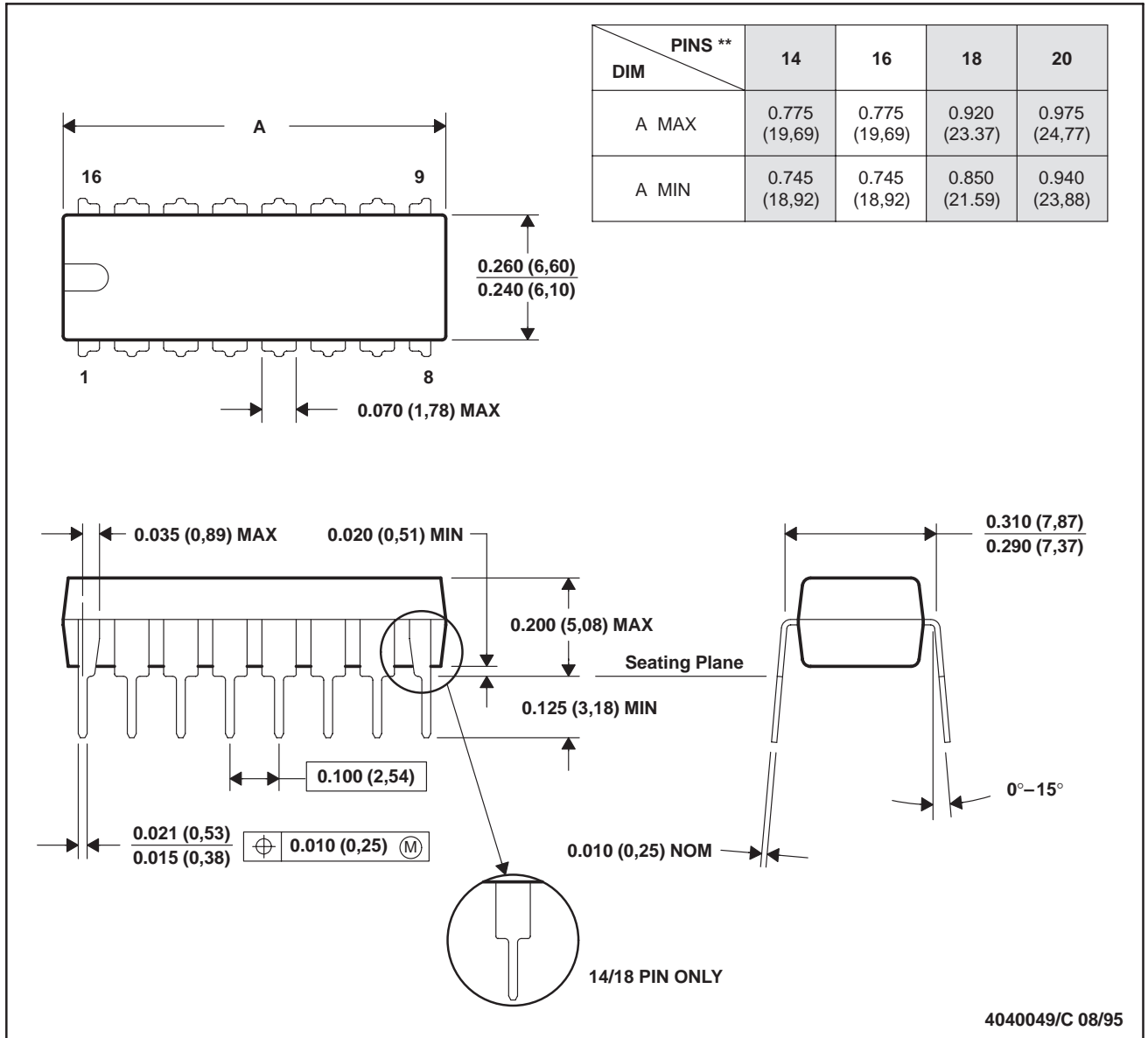
TL1453C DUAL PULSE-WIDTH-MODULATION CONTROL CIRCUIT

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N (R-PDIP-T)**

PLASTIC DUAL-IN-LINE PACKAGE

16 PIN SHOWN



- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. Falls within JEDEC MS-001 (20 pin package is shorter than MS-001.)

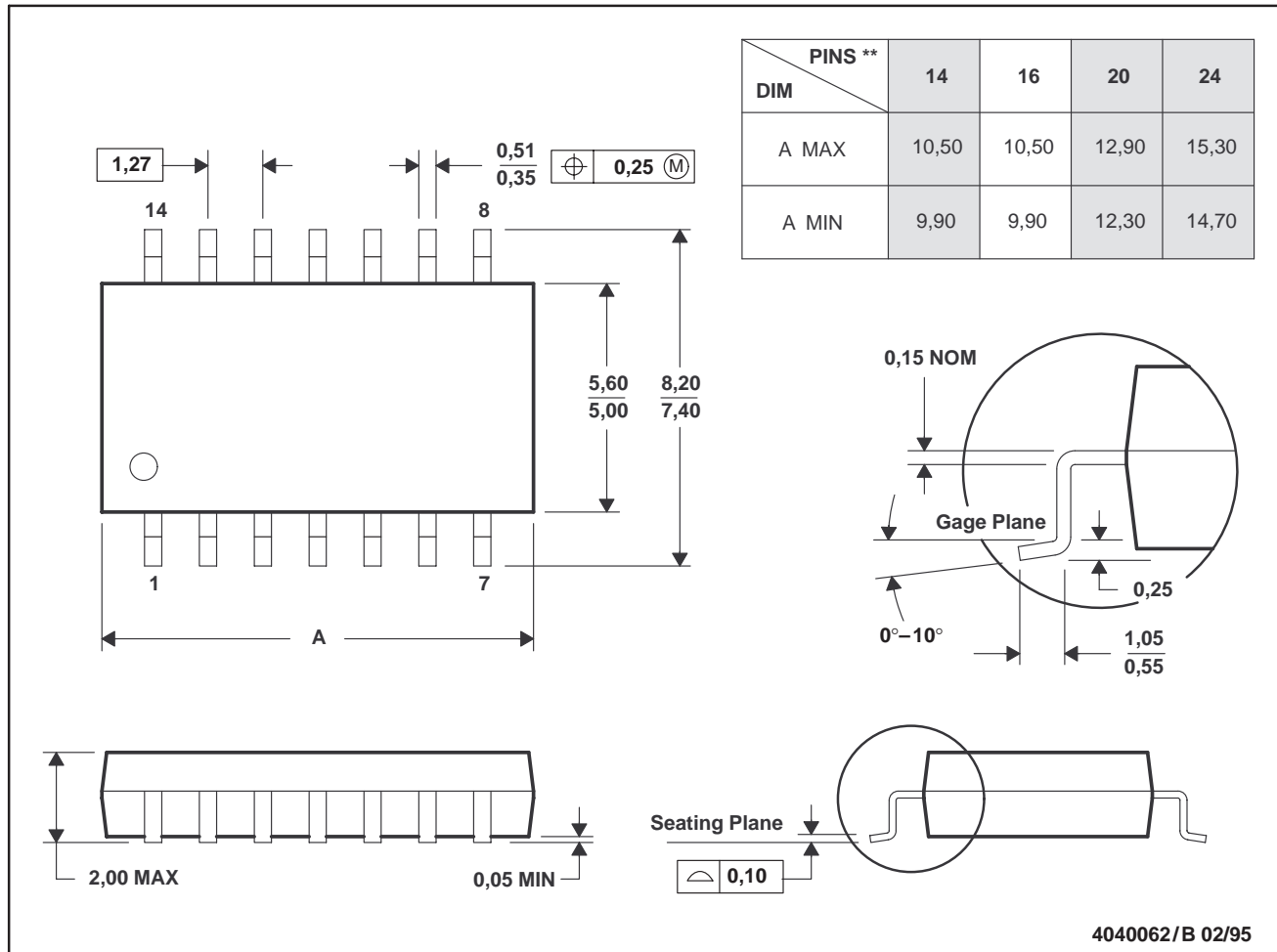
TL1453C DUAL PULSE-WIDTH-MODULATION CONTROL CIRCUIT

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NS (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14 PIN SHOWN



- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

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